

# Cheng-Liang Huang

## List of Publications by Year in descending order

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223  
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225  
docs citations

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times ranked

1476  
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#	ARTICLE	IF	CITATIONS
1	Resistive switching characteristics of sol-gel derived La <sub>2</sub> Zr <sub>2</sub> O <sub>7</sub> thin film for RRAM applications. Journal of Alloys and Compounds, 2022, 899, 163294.	5.5	11
2	Resistive switching characteristics of sol-gel derived ZrCeO <sub>x</sub> thin films for nonvolatile memory applications. Materials Science and Engineering B: Solid-State Materials for Advanced Technology, 2022, 277, 115605.	3.5	2
3	Ultra-low temperature sintering and microwave dielectric properties of Mg-substituted SrCoV <sub>2</sub> O <sub>7</sub> ceramics. Journal of Asian Ceramic Societies, 2022, 10, 188-195.	2.3	5
4	Characterization of nano-sized $\hat{\Gamma}$ -Al <sub>2</sub> O <sub>3</sub> compacts prepared via modified $\hat{\Gamma}$ -Al <sub>2</sub> O <sub>3</sub> @PEG technology. Ceramics International, 2022, , .	4.8	0
5	Ultra-low temperature sintering and temperature stable microwave dielectrics of phase pure AgMgVO <sub>4</sub> ceramics. Journal of the European Ceramic Society, 2022, 42, 3892-3897.	5.7	16
6	Resistive switching properties of amorphous Sm <sub>2</sub> Ti <sub>2</sub> O <sub>7</sub> thin film prepared by RF sputtering for RRAM applications. Journal of Alloys and Compounds, 2022, 910, 164960.	5.5	6
7	A low-loss, low temperature sintering dielectric using Ba <sub>1</sub> -Sr Mg <sub>2</sub> (VO <sub>4</sub> ) <sub>2</sub> ceramics and its applications at microwave frequencies. Materials Science and Engineering B: Solid-State Materials for Advanced Technology, 2021, 268, 115114.	3.5	9
8	The photoluminescence of single-phase warm white-light-emitting luminescence using CaSnO <sub>3</sub> : Ce <sup>3+</sup> / Mn <sup>4+</sup> / Dy <sup>3+</sup> phosphors. Journal of Asian Ceramic Societies, 2021, 9, 1055-1066.	2.3	0
9	Effect of a minute substitution on the structure and microwave dielectric properties of novel LiCoVO <sub>4</sub> ceramics for ULTCC applications. Journal of Asian Ceramic Societies, 2021, 9, 1154-1164.	2.3	7
10	Microwave dielectric properties of novel Na <sub>2</sub> Mg <sub>5-x</sub> Zn <sub>x</sub> (MoO <sub>4</sub> ) <sub>6</sub> (x = 0.09) ceramics for ULTCC applications. Materials Research Bulletin, 2021, 141, 111355.	5.2	19
11	Influence of intrinsic and extrinsic factors on microwave dielectric properties of (Sr <sub>1-x</sub> Mg <sub>x</sub> )V <sub>2</sub> O <sub>6</sub> (x = 0.01-0.09) ceramics for ULTCC applications. Materials Science and Engineering B: Solid-State Materials for Advanced Technology, 2021, 273, 115438.	3.5	8
12	Ultra-low temperature sintering and temperature stable microwave dielectrics of (Mg <sub>1-x</sub> Zn <sub>x</sub> )V <sub>2</sub> O <sub>6</sub> (x = 0.09) Ceramics. Journal of Asian Ceramic Societies, 2021, 9, 106-112.	2.3	14
13	The effects of zinc substitution on the electrical properties of MgNb <sub>2</sub> O <sub>6</sub> thin films. Journal of Asian Ceramic Societies, 2021, 9, 253-261.	2.3	0
14	Electrical properties and current conduction mechanisms of LaGdO <sub>3</sub> thin film by RF sputtering for RRAM applications. Journal of Asian Ceramic Societies, 2020, 8, 948-956.	2.3	2
15	High-Q Li <sub>2</sub> Mg <sub>2</sub> (MoO <sub>4</sub> ) <sub>3</sub> dielectrics for LTCC applications at microwave frequencies. Journal of Asian Ceramic Societies, 2020, 8, 430-436.	2.3	11
16	Resistive Switching Property of Organic-Inorganic Tri-Cation Lead Iodide Perovskite Memory Device. Nanomaterials, 2020, 10, 1155.	4.1	9
17	Microwave dielectric properties of Li <sub>2</sub> M <sub>2</sub> (MoO <sub>4</sub> ) <sub>3</sub> (M = Co, Ni) for LTCC applications. International Journal of Ceramic Engineering & Science, 2020, 2, 130-139.	1.2	5
18	The synthesis and photoluminescence enhancement of sensitizer-doped Li <sub>2</sub> MgTi <sub>3</sub> O <sub>8</sub> :Mn <sup>4+</sup> red phosphor. Journal of Alloys and Compounds, 2019, 787, 440-447.	5.5	20

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19	<i>Ab Initio</i> -Aided Sensitizer Design for Mn <sup>4+</sup> -Activated Mg <sub>2</sub> TiO <sub>4</sub> as an Ultrabright Fluoride-Free Red-Emitting Phosphor. <i>Chemistry of Materials</i> , 2018, 30, 1769-1775.	6.7	25
20	Sol-gel derived TiNb <sub>2</sub> O <sub>7</sub> dielectric thin films for transparent electronic applications. <i>Journal of the American Ceramic Society</i> , 2018, 101, 674-682.	3.8	12
21	Investigation of the microwave dielectric properties of Li <sub>2</sub> ZnTi <sub>5</sub> O <sub>12</sub> ceramics. <i>Journal of Alloys and Compounds</i> , 2016, 678, 102-108.	5.5	12
22	Thin-Film Photoluminescent Properties and the Atomistic Model of Mg <sub>2</sub> TiO <sub>4</sub> as a Non-rare Earth Matrix Material for Red-Emitting Phosphor. <i>Journal of Electronic Materials</i> , 2016, 45, 6214-6221.	2.2	2
23	Structural characteristics and microwave dielectric properties of low-firing Ba(Co <sub>1-x</sub> Mg <sub>x</sub> ) <sub>2</sub> (VO <sub>4</sub> ) <sub>2</sub> thin films. <i>Journal of Applied Physics</i> , 2018, 123, 074101.	5.5	18
24	Sintering temperature dependences of the microwave dielectric properties of (1-x)Ba <sub>0.95</sub> Mn <sub>0.05</sub> TiO <sub>3</sub> microwave dielectric ceramics with a zero temperature coefficient of resonant frequency. <i>Journal of the Ceramic Society of Japan</i> , 2015, 123, 374-377.	1.1	2
25	Characterization and microwave dielectric properties of Mg <sub>2</sub> YVO <sub>6</sub> ceramic. <i>Journal of Alloys and Compounds</i> , 2015, 641, 93-98.	5.5	17
26	Sintering behavior and microwave dielectric properties of ZnCuTiO <sub>4</sub> ceramics. <i>Journal of Alloys and Compounds</i> , 2015, 638, 29-33.	5.5	6
27	The Effects of Annealing Atmosphere on the Electrical Properties of MgNb <sub>2</sub> O <sub>6</sub> /ITO Heterostructures. <i>Journal of the American Ceramic Society</i> , 2015, 98, 580-586.	3.8	2
28	Crystal structure and dielectric properties of xCa(Mg <sub>1/3</sub> Nb <sub>2/3</sub> )O <sub>3</sub> -(1-x)(Ca <sub>0.61</sub> Nd <sub>0.26</sub> )TiO <sub>3</sub> at the microwave frequency. <i>Materials Research Bulletin</i> , 2015, 63, 1-5.	5.2	13
29	Microwave dielectric properties of low-loss (Zn <sub>1-x</sub> Co <sub>x</sub> ) <sub>3</sub> Nb <sub>2</sub> O <sub>8</sub> ceramics for LTCC applications. <i>Journal of Alloys and Compounds</i> , 2015, 620, 18-23.	5.5	13
30	Intense Red Photoluminescence Emission of Sol-gel Derived Nanocrystalline Mg <sub>2</sub> TiO <sub>4</sub> Thin Films. <i>Journal of the American Ceramic Society</i> , 2014, 97, 358-360.	3.8	9
31	Resistive Switching Behaviors of Sol-gel Derived MgNb <sub>2</sub> O <sub>6</sub> Thin Films on ITO/glass Substrate. <i>Journal of the American Ceramic Society</i> , 2014, 97, 3544-3548.	3.8	3
32	Low loss and temperature stable microwave dielectrics using Li <sub>2</sub> (Mg <sub>1-x</sub> Al <sub>x</sub> )Ti <sub>3</sub> O <sub>8</sub> (A <sub>2</sub> =Zn, Co;). <i>Journal of Applied Physics</i> , 2014, 115, 074101.	5.5	13
33	Thermal Reaction of Cristobalite in Nano-SiO <sub>2</sub> /Al <sub>2</sub> O <sub>3</sub> Powder Systems for Mullite Synthesis. <i>Journal of the American Ceramic Society</i> , 2014, 97, 2431-2438.	3.8	10
34	High-Q microwave dielectrics in the (Mg <sub>1-x</sub> Zn <sub>x</sub> ) <sub>4</sub> Ta <sub>2</sub> O <sub>9</sub> ceramics. <i>Journal of Alloys and Compounds</i> , 2014, 590, 494-499.	5.5	8
35	High-Q microwave dielectrics in low-temperature sintered (Zn <sub>1-x</sub> Ni <sub>x</sub> ) <sub>3</sub> Nb <sub>2</sub> O <sub>8</sub> ceramics. <i>Journal of the European Ceramic Society</i> , 2014, 34, 277-284.	5.7	60
36	Dielectric properties and crystal structure of Mg <sub>2</sub> Ta <sub>2</sub> O <sub>9</sub> ceramics with Mg <sup>2+</sup> substituted by Co <sup>2+</sup> . <i>Journal of the Ceramic Society of Japan</i> , 2014, 122, 556-560.	1.1	4

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37	Ultra low loss microwave dielectric properties of Non-stoichiometry $[(\text{Mg}_{0.7}\text{Zn}_{0.3})_{0.95}\text{Co}_{0.05}]_{1+x}(\text{Ti}_{1-x})_{x/2}\text{O}_6$ ceramics. Journal of the Ceramic Society of Japan, 2014, 122, 762-767.		
38	New material properties and microstructure of $x\text{La}(\text{Mg}_{1/2}\text{Ti}_{1/2}\text{O}_3)_{0.6}\text{Sm}_{0.4}\text{TiO}_3$ ceramics at microwave frequency. Journal of the Ceramic Society of Japan, 2014, 122, 951-954.		
39	Influence of Mg substitutions for Zn on the phase relation and microwave dielectric properties of $(\text{Zn}_{1-x}\text{Mg}_x)_3\text{Nb}_2\text{O}_8$ ( $x=0.02\sim 1.0$ ) system. Journal of Alloys and Compounds, 2013, 581, 257-262.	5.5	16
40	Miniaturization of ring resonator bandpass filters using dielectric ceramic substrates. Microwave and Optical Technology Letters, 2013, 55, 660-663.	1.4	3
41	Sol-Gel-Derived Amorphous- $\text{MgNb}_2\text{O}_6$ Thin Films for Transparent Microelectronics. Journal of the American Ceramic Society, 2013, 96, 3375-3378.	3.8	7
42	Strong Near-Infrared Photoluminescence Emission of (003)-Oriented $\text{MgTiO}_3$ Thin Films. Journal of the American Ceramic Society, 2013, 96, 2065-2068.	3.8	13
43	Low-loss microwave dielectric ceramics in the $(\text{Co}_{1-x}\text{Zn}_x)\text{TiO}_3$ ( $x=0\sim 0.1$ ) system. Journal of Alloys and Compounds, 2012, 515, 8-11.	5.5	21
44	Two-poles compact microstrip bandpass filter with sharp transition bands using high permittivity substrate. Microwave and Optical Technology Letters, 2012, 54, 1683-1686.	1.4	0
45	Microwave Dielectric Properties of $(\text{Mg}_{0.95}\text{Ni}_{0.05})_{1-x}(\text{Ca}_{0.8}\text{Sm}_{0.2})_x\text{TiO}_3$ Ceramic System With Near-Zero Temperature Coefficient. International Journal of Applied Ceramic Technology, 2012, 9, 447-453.	2.1	8
46	Microwave Dielectric Characteristics of $(\text{Mg}_{0.95}\text{M}_{0.05})\text{Ta}_2\text{O}_6$ ( $\text{M}=\text{Ni}, \text{Zn}, \text{Mn}$ ) Ceramic Series. Materials Letters, 2012, 76, 28-31.	2.6	15
47	Dielectric properties of high-Q $(\text{Mg}_{1-x}\text{Zn}_x)_1.8\text{Ti}_{1.1}\text{O}_4$ ceramics at microwave frequency. Journal of the European Ceramic Society, 2012, 32, 2365-2371.	5.7	19
48	High-Q dielectrics using ZnO-modified $\text{Li}_2\text{TiO}_3$ ceramics for microwave applications. Journal of the European Ceramic Society, 2012, 32, 3287-3295.	5.7	61
49	Effect of $\text{CaTiO}_3$ addition on microwave dielectric properties of $\text{Mg}_2(\text{Ti}_{0.95}\text{Sn}_{0.05})\text{O}_4$ ceramics. Journal of Alloys and Compounds, 2011, 509, 4247-4251.	5.5	19
50	Crystal structure and dielectric properties of $\text{La}(\text{Mg}_{0.5}\text{Ti}_{0.5})\text{O}_3\text{Ca}_{0.8}\text{Sm}_{0.4}/3\text{TiO}_3$ solid solution system at microwave frequencies. Journal of Alloys and Compounds, 2011, 509, 426-430.	5.5	5
51	Low-loss microwave dielectrics using $(\text{Mg}_{1-x}\text{Zn}_x)_4\text{Nb}_2\text{O}_9$ ( $x=0.02\sim 0.08$ ) solid solutions. Journal of Alloys and Compounds, 2011, 509, 2269-2272.	5.5	11
52	High-dielectric-constant and low-loss microwave dielectric in the $(1-x)\text{La}(\text{Mg}_{0.5}\text{Ti}_{0.5})\text{O}_3\text{Ca}_{0.8}\text{Sr}_{0.2}\text{TiO}_3$ solid solution system. Journal of Alloys and Compounds, 2011, 509, L99-L102.	5.5	7
53	High-Q microwave dielectrics in the $(\text{Mg}_{1-x}\text{Zn}_x)\text{Al}_2\text{O}_4$ ( $x=0\sim 0.1$ ) system. Journal of Alloys and Compounds, 2011, 509, L150-L152.	5.5	16
54	Phase evolution and microwave dielectric properties of $\text{TiO}_2$ -modified $(\text{Mg}_{0.95}\text{Co}_{0.05})_2\text{TiO}_4$ ceramics. Journal of Alloys and Compounds, 2011, 509, 6273-6275.	5.5	3

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55	Low-firable high-K dielectric in the $Zr_x(\text{Zn}_{1/3}\text{Nb}_{2/3})_{1-x}\text{TiO}_4$ ceramic system. <i>Journal of Alloys and Compounds</i> , 2011, 509, L293-L295.	5.5	10
56	Low-loss microwave dielectrics using rock salt oxide $\text{Li}_2\text{MgTiO}_4$ . <i>Journal of Alloys and Compounds</i> , 2011, 509, L308-L310.	5.5	61
57	The effect of non-stoichiometry on the microstructure and microwave dielectric properties of the $\text{Mg}_{1-x}\text{TiO}_3+x\text{TiO}_2$ ceramics. <i>Journal of Alloys and Compounds</i> , 2011, 509, 9702-9707.	5.5	12
58	Structure, Dielectric Properties, and Applications of $\text{CaTiO}_3$ -Modified $\text{Ca}_4\text{MgNb}_2\text{TiO}_{12}$ Ceramics at Microwave Frequency. <i>Journal of the American Ceramic Society</i> , 2011, 94, 1824-1828.	3.8	9
59	$\text{MgTiO}_3$ (003) Thin Film Deposited on Sapphire (0001) by Sputtering. <i>Journal of the American Ceramic Society</i> , 2011, 94, 363-366.	3.8	7
60	Textured Magnesium Titanate as Gate Oxide for GaN-Based Metal-Oxide-Semiconductor Capacitor. <i>Journal of the American Ceramic Society</i> , 2011, 94, 1005-1007.	3.8	15
61	Low-Loss Microwave Dielectrics in the $(\text{Mg}_{1-x}\text{Co}_x)_{1.8}\text{Ti}_{1.1}\text{O}_4$ ( $x=0.03\sim 1.00$ ) Solid Solutions. <i>Journal of the American Ceramic Society</i> , 2011, 94, 2963-2967.	3.8	13
62	High $Q$ Microwave Dielectric Ceramics in the $(\text{Li}_2\text{Zn})_{1-x}\text{A}_x$ ( $\text{A}=\text{Mg}, \text{Co}$ ; $x=0.02\sim 0.1$ ) System. <i>Journal of the American Ceramic Society</i> , 2011, 94, 4146-4149.	3.8	45
63	Temperature Compensating Microwave Dielectric Based on the $(\text{Mg}_{0.95}\text{Ni}_{0.05})\text{TiO}_3$ ( $\text{La}_{0.5}\text{Na}_{0.5}$ ) $\text{TiO}_3$ Ceramic System. <i>International Journal of Applied Ceramic Technology</i> , 2010, 7, E64.		6
64	A new dielectric material system using $(1-x)(\text{Mg}_{0.95}\text{Co}_{0.05})_2\text{TiO}_4-x\text{Ca}_{0.8}\text{Sm}_{0.4/3}\text{TiO}_3$ at microwave frequencies. <i>Materials Chemistry and Physics</i> , 2010, 120, 217-220.	4.0	6
65	Microwave dielectric properties of $\text{Mg}_{1.8}\text{Ti}_{1.1}\text{O}_4$ ceramics. <i>Materials Letters</i> , 2010, 64, 885-887.	2.6	5
66	A new low-loss microwave dielectric using $(\text{Ca}_{0.8}\text{Sr}_{0.2})\text{TiO}_3$ -doped $\text{MgTiO}_3$ ceramics. <i>Materials Letters</i> , 2010, 64, 2585-2588.	2.6	34
67	Microstrip ring resonator bandpass filters using ceramic substrate. <i>Microwave and Optical Technology Letters</i> , 2010, 52, 218-220.	1.4	0
68	Band-pass filters using high-permittivity ceramics substrate. <i>Microwave and Optical Technology Letters</i> , 2010, 52, 2344-2347.	1.4	1
69	High-dielectric-constant and low-loss microwave dielectric in the $\text{Ca}(\text{Mg}_{1/3}\text{Ta}_{2/3})\text{O}_3-x(\text{Ca}_{0.8}\text{Sr}_{0.2})\text{TiO}_3$ solid solution system. <i>Materials Science and Engineering B: Solid-State Materials for Advanced Technology</i> , 2010, 167, 142-146.	3.5	8
70	Microwave Dielectric Properties of $(\text{Mg}_{0.95}\text{Ni}_{0.05})\text{TiO}_3-x\text{SrTiO}_3$ Ceramics with a Near-Zero Temperature Coefficient of Resonant Frequency. <i>International Journal of Applied Ceramic Technology</i> , 2010, 7, 207-216.	2.1	20
71	Microwave Dielectric Properties of $(\text{Mg}_{1-x}\text{Ni}_x)_2\text{TiO}_4$ ( $x=0.02\sim 0.1$ ) Ceramics. <i>International Journal of Applied Ceramic Technology</i> , 2010, 7, E163.	2.1	30
72	Synthesis, Crystal Structure, and Microwave Dielectric Properties of $(\text{Mg}_{1-x}\text{Co}_x)_2\text{Ta}_2\text{O}_6$ Solid Solutions. <i>Journal of the American Ceramic Society</i> , 2010, 93, 470-473.	3.8	29

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73	Phase Relation and Microwave Dielectric Properties of $(\text{Zn}_{1-x}\text{Co}_x)_2\text{O}_6$ System. Journal of the American Ceramic Society, 2010, 93, 1248-1251.	3.8	37
74	Low-loss Microwave Dielectrics in the Spinel-structured $(\text{Mg}_{1-x}\text{Ni}_x)_2\text{O}_4$ Solid Solutions. Journal of the American Ceramic Society, 2010, 93, 1999-2003.	3.8	46
75	Low-temperature Sintering Microwave Dielectrics Using CuO-doped $\text{Zn}(\text{Nb}_{0.95}\text{Ta}_{0.05})_2\text{O}_6$ Ceramics. Journal of the American Ceramic Society, 2010, 93, 2755-2759.	3.8	8
76	High Dielectric Constant and Low-loss Microwave Dielectric Ceramics Using $(\text{Zn}_{0.95}\text{M}_{2+0.05})\text{Ta}_2\text{O}_6$ ( $\text{M}_{2+}=\text{Mn}, \text{Bi}, \text{ET}, \text{Q}, \text{O}, \text{r}, \text{g}, \text{BT}$ )	3.8	10
77	Characterization and dielectric behavior of V <sub>2</sub> O <sub>5</sub> -doped 0.9Mg <sub>0.95</sub> Co <sub>0.05</sub> TiO <sub>3</sub> –0.1Ca <sub>0.6</sub> La <sub>0.8</sub> /3TiO <sub>3</sub> ceramic system at microwave frequency. Journal of Alloys and Compounds, 2010, 489, 170-174.	5.5	19
78	New dielectric material system of Nd(Mg <sub>1/2</sub> Ti <sub>1/2</sub> )O <sub>3</sub> –CaTiO <sub>3</sub> with V <sub>2</sub> O <sub>5</sub> addition for microwave applications. Journal of Alloys and Compounds, 2010, 489, 719-721.	5.5	14
79	Improved high Q value of $(1-x)\text{Ca}(\text{Mg}_{1/3}\text{Ta}_{2/3})\text{O}_3$ – $x\text{Ca}_{0.8}\text{Sm}_{0.4}/3\text{TiO}_3$ solid solution with zero temperature coefficient of resonant frequency. Journal of Alloys and Compounds, 2010, 494, 205-209.	5.5	27
80	Low-loss microwave dielectrics in the $\text{Mg}_2(\text{Ti}_{0.95}\text{Sn}_{0.05})\text{O}_4$ – $(\text{Ca}_{0.8}\text{Sr}_{0.2})\text{TiO}_3$ ceramic system. Journal of Alloys and Compounds, 2010, 502, 324-328.	5.5	3
81	A new low-loss dielectric using CaTiO <sub>3</sub> -modified (Mg <sub>0.95</sub> Mn <sub>0.05</sub> )TiO <sub>3</sub> ceramics for microwave applications. Journal of Alloys and Compounds, 2010, 499, 48-52.	5.5	22
82	Improvements in the sintering behavior and microwave dielectric properties of Mg <sub>4</sub> Nb <sub>2</sub> O <sub>9</sub> by adding Fe <sub>2</sub> O <sub>3</sub> . Journal of Alloys and Compounds, 2010, 495, L5-L7.	5.5	18
83	A novel low-loss microwave dielectric using (Ca <sub>0.8</sub> Sr <sub>0.2</sub> )TiO <sub>3</sub> -modified (Mg <sub>0.95</sub> Co <sub>0.05</sub> ) <sub>2</sub> TiO <sub>4</sub> ceramics. Journal of Alloys and Compounds, 2010, 496, L10-L13.	5.5	8
84	Microwave dielectric properties of $x(\text{Mg}_{0.7}\text{Zn}_{0.3})_{0.95}\text{Co}_{0.05}\text{TiO}_3$ – $(1-x)\text{Ca}_{0.8}\text{Sr}_{0.2}\text{TiO}_3$ ceramics with a zero temperature coefficient of resonant frequency. Journal of Alloys and Compounds, 2010, 503, 392-396.	5.5	11
85	Characterization and dielectric behavior of B <sub>2</sub> O <sub>3</sub> -doped 0.9Mg <sub>0.95</sub> Co <sub>0.05</sub> TiO <sub>3</sub> –0.1Ca <sub>0.6</sub> La <sub>0.8</sub> /3TiO <sub>3</sub> ceramic system at microwave frequency. Journal of Alloys and Compounds, 2010, 504, 228-232.	5.5	17
86	Dielectric properties of magnesium oxide at microwave frequency. Journal of Alloys and Compounds, 2010, 504, 284-287.	5.5	19
87	Dielectric properties of B <sub>2</sub> O <sub>3</sub> -doped 0.92(Mg <sub>0.95</sub> Co <sub>0.05</sub> ) <sub>2</sub> TiO <sub>4</sub> –0.08(Ca <sub>0.8</sub> Sr <sub>0.2</sub> )TiO <sub>3</sub> ceramics for microwave applications. Journal of Alloys and Compounds, 2010, 505, 291-296.	5.5	12
88	Sintering Behavior and Dielectric Properties of ZnNb <sub>2</sub> O <sub>6</sub> –TiO <sub>2</sub> Ceramic System at Microwave Frequency. Japanese Journal of Applied Physics, 2009, 48, 100203.	1.5	3
89	Dielectric properties of a new ceramic system $(1-x)\text{Mg}_4\text{Nb}_2\text{O}_9$ – $x\text{CaTiO}_3$ at microwave frequency. Materials Research Bulletin, 2009, 44, 1111-1115.	5.2	19
90	Effect of CuO addition to Nd(Zn <sub>1/2</sub> Ti <sub>1/2</sub> )O <sub>3</sub> ceramics on sintering behavior and microwave dielectric properties. Materials Letters, 2009, 63, 103-105.	2.6	19

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91	Quasi-elliptic function filters with a dual-passband response with high-permittivity ceramics substrate. Microwave and Optical Technology Letters, 2009, 51, 245-248.	1.4	2
92	End-coupled microstrip slow-wave resonator filters using high-permittivity ceramic substrate. Microwave and Optical Technology Letters, 2009, 51, 1613-1615.	1.4	0
93	Microwave dielectric properties of $(1-x)(\text{Mg}_{0.95}\text{Co}_{0.05})\text{TiO}_3-x(\text{Na}_{0.5}\text{La}_{0.5})\text{TiO}_3$ ceramic system. Current Applied Physics, 2009, 9, 1355-1359.	2.4	7
94	High-Q Microwave Dielectrics in the $(\text{Mg}_{1-x}\text{Co}_x)_2\text{TiO}_4$ Ceramics. Journal of the American Ceramic Society, 2009, 92, 379-383.	3.8	72
95	Low Dielectric Loss Ceramics in the $\text{ZnAl}_2\text{O}_4-x\text{TiO}_2$ System as a $\epsilon_r$ Compensator. Journal of the American Ceramic Society, 2009, 92, 119-124.	3.8	50
96	Phase Evolution and Dielectric Properties of $(\text{Mg}_{0.95}\text{M}_{0.05})\text{Ti}_2\text{O}_5$ ( $\text{M}=\text{Co}, \text{Ni}, \text{and Zn}$ ) Ceramics at Microwave Frequencies. Journal of the American Ceramic Society, 2009, 92, 384-388.	3.8	36
97	Low-Loss Microwave Dielectric Ceramics Using $(\text{Mg}_{1-x}\text{Mn}_x)_2\text{TiO}_4$ ( $x=0.02-0.1$ ) Solid Solution. Journal of the American Ceramic Society, 2009, 92, 675-678.	3.8	58
98	Low-Loss Microwave Dielectrics Using $\text{Mg}_2(\text{Ti}_{1-x}\text{Sn}_x)\text{O}_4$ ( $x=0.01-0.09$ ) Solid Solution. Journal of the American Ceramic Society, 2009, 92, 2237-2241.	3.8	33
99	Reduced Dielectric Loss of Modified $\text{ZnNb}_2\text{O}_6$ Ceramics by Substituting $\text{Nb}_5+$ with $\text{Ta}_5+$ . Journal of the American Ceramic Society, 2009, 92, 1845-1848.	3.8	15
100	A Novel Temperature-Compensated Microwave Dielectric $(1-x)(\text{Mg}_{0.95}\text{Ni}_{0.05})\text{Ti}_3-x\text{Ca}_{0.6-x}\text{La}_{0.8-x}\text{TiO}_3$ Ceramics System. International Journal of Applied Ceramic Technology, 2009, 6, 562-570.	3.8	13
101	The effect of RF power and deposition temperature on the structure and electrical properties of $\text{Mg}_4\text{Ta}_2\text{O}_9$ thin films prepared by RF magnetron sputtering. Journal of Crystal Growth, 2009, 311, 627-633.	1.5	6
102	Dielectric properties of $\text{Mg}_{0.95}\text{Ni}_{0.05}\text{TiO}_3$ ceramic modified by $\text{Nd}_{0.5}\text{Na}_{0.5}\text{TiO}_3$ at microwave frequencies. Current Applied Physics, 2009, 9, 1042-1045.	2.4	9
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217	Microwave dielectric properties and microstructures of BaO modified CaO-Li <sub>2</sub> O-Sm <sub>2</sub> O <sub>3</sub> -TiO <sub>2</sub> ceramics. Journal of Materials Science Letters, 2000, 19, 2197-2199.	0.5	2
218	Dielectric Properties of CaTiO <sub>3</sub> Ca(Mg <sub>1/3</sub> Nb <sub>2/3</sub> )O <sub>3</sub> Ceramic System at Microwave Frequency. Japanese Journal of Applied Physics, 2000, 39, 6608-6611.	1.5	30
219	Pseudoelliptic bandpass filter realization using attenuation pole resonator. Microwave and Optical Technology Letters, 1999, 23, 275-277.	1.4	1
220	Low loss ladder-type IF SAW filter, used Au-Ge-Ni electrode. , 0, , .		0
221	Growth of AlN thin film on Mo electrode for FBAR application. , 0, , .		1
222	Compact 2.5 GHz Circularly Polarized Antenna Using High Permittivity Substrate. , 0, , .		1
223	Microstrip Rectangular Ring Bandpass Filter Design Using High Permittivity Substrate. , 0, , .		2